

AAP Gen 7 (TO-240AA) Power Modules Schottky Rectifier, 200 A



AAP Gen 7 (TO-240AA)

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation
- UL approved file E78996
- Low thermal resistance
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- Easy mounting on heatsink

ELECTRICAL DESCRIPTION / APPLICATIONS

The VS-VSKDS409/150 Schottky rectifier doubler module has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	200 A
V_R	150 V
Package	AAP Gen 7 (TO-240AA)
Circuit configuration	Two diodes doubler circuit

MECHANICAL DESCRIPTION

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	200	A
V_{RRM}		150	V
I_{FSM}	$t_p = 5 \mu s$ sine	20 000	A
V_F	200 A _{pk} , $T_J = 125 \text{ }^\circ\text{C}$	0.85	V
T_J	Range	-55 to +175	°C

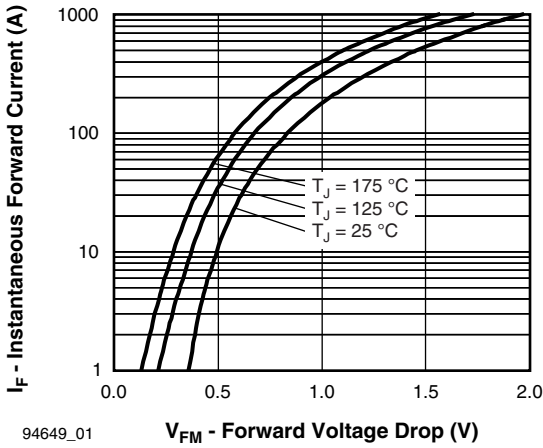
VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-VSKDS409/150	UNITS
Maximum DC reverse voltage	V_R	150	V
Maximum static peak reverse voltage	V_{RRM}		



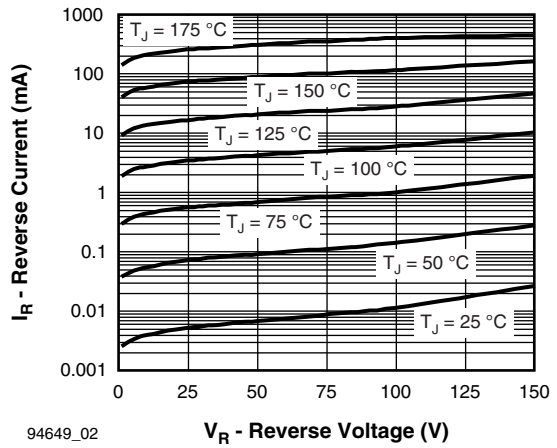
ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	50 % duty cycle at $T_C = 105\text{ }^\circ\text{C}$, rectangular waveform		200	A
Maximum peak one cycle non-repetitive surge current	I_{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V_{RRM} applied	20 000	
		10 ms sine or 6 ms rect. pulse		2300	
Non-repetitive avalanche energy	E_{AS}	$T_J = 25\text{ }^\circ\text{C}$, $I_{AS} = 1.8\text{ A}$, $L = 10\text{ mH}$		15	mJ
Repetitive avalanche current	I_{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		1	A
Maximum dynamic peak reverse voltage	V_{AV}	$T_J = 25\text{ }^\circ\text{C}$, $I_{AS} = 1.8\text{ A}$, $L = 10\text{ mH}$		170	V

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V_{FM}	200 A	$T_J = 25\text{ }^\circ\text{C}$	1.03	V
		400 A		1.33	
		200 A	$T_J = 125\text{ }^\circ\text{C}$	0.85	
		400 A		1.13	
Maximum reverse leakage current	I_{RM}	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	6	mA
		$T_J = 125\text{ }^\circ\text{C}$		85	
Maximum junction capacitance	C_T	$V_R = 5\text{ V}_{DC}$ (test signal range 100 kHz to 1 MHz), $25\text{ }^\circ\text{C}$		6000	pF
Typical series inductance	L_S	Measured lead to lead 5 mm from package body		5.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/ μs
Maximum RMS insulation voltage	V_{INS}	50 Hz		3000 (1 min)	V
				3600 (1 s)	

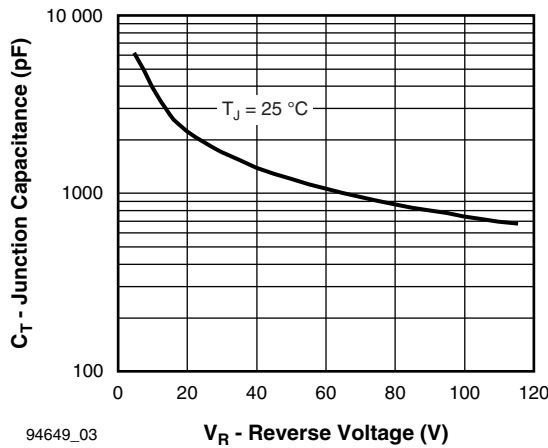
THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction and storage temperature range	T_J, T_{Stg}			-55 to +175	$^\circ\text{C}$
Maximum thermal resistance, junction to case per leg	R_{thJC}	DC operation		0.32	$^\circ\text{C}/\text{W}$
Typical thermal resistance, case to heatsink per module	R_{thCS}			0.1	
Approximate weight				75	g
				2.7	oz.
Mounting torque $\pm 10\%$	to heatsink	A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the spread of the compound.		4	Nm
	busbar			3	
Case style		JEDEC [®]		TO-240AA compatible	



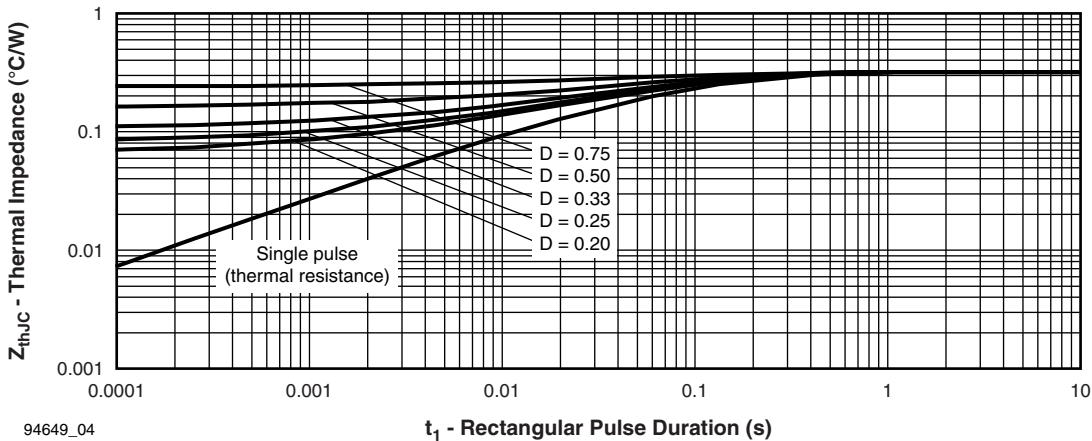
94649_01 **V_{FM} - Forward Voltage Drop (V)**
 Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)



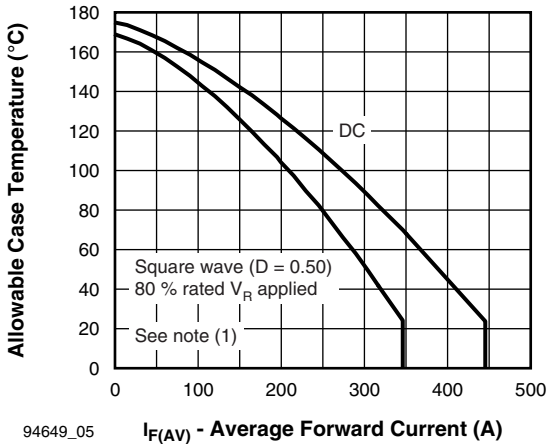
94649_02 **V_R - Reverse Voltage (V)**
 Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



94649_03 **V_R - Reverse Voltage (V)**
 Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



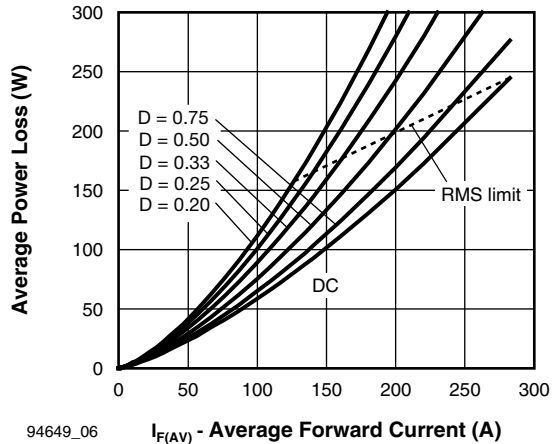
94649_04 **t₁ - Rectangular Pulse Duration (s)**
 Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Diode)



94649_05

$I_{F(AV)}$ - Average Forward Current (A)

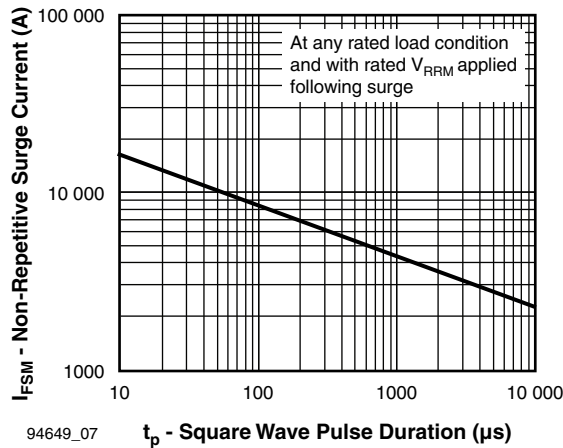
Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)



94649_06

$I_{F(AV)}$ - Average Forward Current (A)

Fig. 6 - Forward Power Loss Characteristics (Per Leg)



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t_p - Square Wave Pulse Duration (μ s)

Fig. 7 - Maximum Non-Repetitive Surge Current

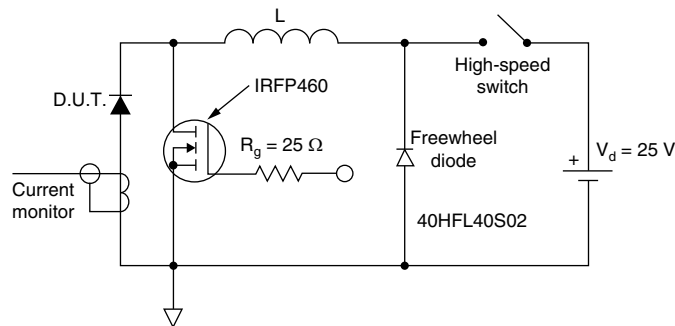


Fig. 8 - Unclamped Inductive Test Circuit

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;
 P_d = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 P_{dREV} = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R

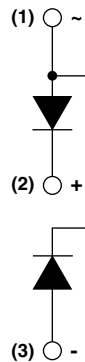
ORDERING INFORMATION TABLE

Device code	VS-VS	KD	S	40	9	/	150
	①	②	③	④	⑤		⑥

- 1** - Vishay Semiconductors product
- 2** - Circuit configuration:
KD = ADD-A-PAK - 2 diodes doubler circuit
- 3** - S = Schottky diode
- 4** - Average current rating (40 = 400 A) ⁽¹⁾
- 5** - Product silicon identification
- 6** - Voltage rating (150 = 150 V)

Note

⁽¹⁾ For KD configuration average current rating per module is 200 A

CIRCUIT CONFIGURATION

LINKS TO RELATED DOCUMENTS

Dimensions	www.vishay.com/doc?95369
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ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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